

General Description

Maxim's MAX332, DG202 and DG212 are normally open, quad single-pole-single-throw (SPST) analog switches. These CMOS switches can be continuously operated with power supplies ranging from ±4.5V to ±18V. Maxim guarantees that the MAX332 and DG202/212 will not latch up if their power supplies are disconnected with input signals still connected.

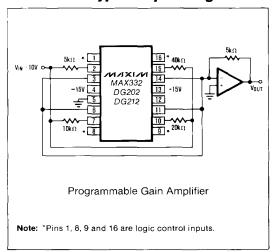
The MAX332 and DG202/DG212 are similar to the DG201 and DG211 except for inverted control inputs. All devices have guaranteed break-before-make switching as well as essentially constant on resistance over the analog signal range. All switches conduct current in either direction and add no offset to the output signal.

Compared to the original manufacturers products, Maxim's MAX332 and DG202/DG212 consume very little power, making them ideally suited for portable applications. Maxim has also eliminated the need for the third logic power supply (V_L), required when operating the original manufacturer's DG212, without sacrificing compatibility.

Applications

Analog Multiplexers
Programmable Gain Amplifiers
Communications Systems
Sample/Holds
Automatic Test Equipment
PBX, PABX

Typical Operating Circuit



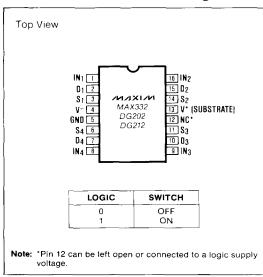
Features

- ♦ Improved 2nd Source! (See pages 3 and 5 for "MAXIM Advantage"")
- ♦ Guaranteed ±4.5V to ±18V Operation
- ♦ No V_L Supply Required
- Non-Latching with Supplies Turned-off and Input Signals Present
- ◆ CMOS and TTL Logic Compatible
- ♦ Monolithic, Low Power CMOS Design

Ordering Information

PART	TEMP. RANGE	PACKAGE
MAX332MJE	-55°C to +125°C	16 Lead CERDIP
DG202C/D	0°C to +70°C	Dice
DG202CJ	0°C to +70°C	16 Lead Plastic DIP
DG202CSE	0°C to +70°C	16 Lead Small Outline
DG202CK	0°C to +70°C	16 Lead CERDIP
DG202BSE	-25°C to +85°C	16 Lead Small Outline
DG202BK	-25°C to +85°C	16 Lead CERDIP
DG202AK	-55°C to +125°C	16 Lead CERDIP
DG212C/D	0°C to +70°C	Dice
DG212CJ	0°C to +70°C	16 Lead Plastic DIP
DG212CSE	0°C to +70°C	16 Lead Small Outline

Pin Configuration



Maxim Integrated Products 1

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ABSOLUTE MAXIMUM RATINGS (DG212)

V ⁺ to V ⁻ 40V	S
V _{IN} to Ground V ⁻ , V ⁺	C
V _L to Ground0.3V, 25V	F
V _S or V _D to V ⁺ 0, -40V	
V _S or V _D to V ⁻ 0, 40V	
V ⁺ to Ground	
V ⁻ to Ground25V	N
Current, Any Terminal Except S or D	
Continuous Current, S or D	
Peak Current, S or D	
(Pulsed at 1msec, 10% duty cycle max) 70mA	

Storage Temperature65°C to +125	°C
Operating Temperature 0°C to +70	ľ°C
Power Dissipation (Note 1)	
16 Pin Plastic DIP (Note 2)	ηW
16 Pin Small Outline (SE) (Note 3) 400n	nW

Note 1: Device mounted with all leads soldered to PC board.

Note 2: Derate 6.5mW/°C above +25°C. Note 3: Derate 7mW/°C above +25°C.

Stresses listed under "Absolute Maximum Ratings" may be applied (one at a time) to devices without resulting in permanent damage. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS (DG212)

(V⁺ = +15V, V⁻ = -15V, GND = 0V, T_A = +25°C, unless otherwise noted)

						LIMITS			
	PARAMETER	SYMBOL	TES	T CONDITIONS	MIN (Note 4)	TYP (Note 5)	MAX	UNITS	
	Analog Signal Range	V _{ANALOG}			-15		15	V	
	Drain-Source ON Resistance	r _{DS (on)}	V _D = ±10V, V	I _{IN} = 2.4V, I _S = 1mA		115	175	Ω	
	Source OFF Leakage Current		V _{IN} = 0.8V	V _S = 14V, V _D = -14V		0.01	5.0		
SWITCH		s (off)	VIN - 0.6V	V _S = -14V, V _D = 14V	-5.0	-0.02			
	Drain OFF Leakage Current)/ = 0.0\/	V _S = 14V, V _D = -14V		0.01	5.0	1	
Ś	Drain OFF Leakage Current	D (off)	$V_{iN} = 0.8V$	V _S = -14V, V _D = 14V	-5.0	-0.02		nA	
	Drain ON Leakage Current	1,	V _S = V _D = 14	V, V _{IN} = 2.4V		0.1	5.0	1	
	(Note 6)	l _D (on)	V _S = V _D = -1	4V, V _{IN} = 2.4V	-5.0	-0.15			
	Input Current With Input		V _{IN} = 2.4V		-1.0	-0.0004			
INPUT	Voltage High				0.003		1.0	μΑ	
Ž	Input Current With Input Voltage Low	I _{INL}	V _{IN} = 0V		-1.0	-0.0004		, m	
	Turn-ON Time	ton	Sec	Switching Time	T	460	1000		
	Turn-OFF Time	t _{off1}		Test Circuit		360	500	ns	
	lum-Off Time	t _{off2}	V _S = 2V	$R_L = 1k\Omega$, $C_L = 35pF$		450	_	1	
Ę	Source OFF Capacitance	C _{S (off)}	V _S = 0V, V _{IN}	= 0V, f = 1MHz		5			
DYNAMIC	Drain OFF Capacitance	C _{D (off)}	$V_D = 0V, V_{IN}$	= 0V, f = 1MHz		5		pF	
Ā	Channel ON Capacitance	C _{D+S(on)}	V _D = V _S = 5\	/, V _{IN} = 0V, f = 1MHz		16			
	OFF Isolation (Note 7)	OIRR	V - 0V D	- 11:0 0 45:5		70			
	Crosstalk (Channel to Channel)	CCRR	V _{IN} = UV, H _L V _S = 1VRMS	= 1kΩ, C _L = 15pF, i, f = 100kHz		90		dB	
<u></u>	Positive Supply Current	1+				0.35	0.48		
SUPPLY	Negative Supply Current	1-	V _{IN} = 0V and	12.4V		0.30	0.48	mA	
SU	Logic Supply Current	I _L				0.5	1,2	┤	

Note 4: The algebraic convention whereby the most negative value is a minimum, and the most positive is a maximum, is used in this

Note 5: Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.

Note 6: I_{D(on)} is leakage from driver into "ON" switch.

Note 7: OFF Isolation = 20 $\log \frac{V_S}{V_D}$, V_S = input to OFF switch, V_D = output.

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♦ Significantly Reduced Power Consumption

- ♦ Third (Logic) Supply Not Required
- Fault Protected

ABSOLUTE MAXIMUM RATINGS (DG212): This device conforms to the Absolute Maximum Ratings on the adjacent page.

ELECTRICAL CHARACTERISTICS (DG212): Specifications below satisfy or exceed all "tested" parameters on adjacent page.

(V⁺ = +15V, V⁻ = -15V, GND = 0V, T_A = +25°C, unless otherwise noted)

						LIMITS		
	PARAMETER	SYMBOL	TES	T CONDITIONS	MIN (Note 4)	TYP (Note 5)	MAX	UNITS
	Analog Signal Range	V _{ANALOG}			-15		15	V
	Drain-Source ON Resistance	r _{DS (on)}	V _D = ±10V, V	/ _{IN} = 2.4V, I _S = 1mA		115	175	Ω
_	Sauran OFF Lankaga Current		V _{IN} = 0.8V	V _S = 14V, V _D = -14V		0.01	5.0	
호	Source OFF Leakage Current	S (off)	V _{IN} - 0.6V	V _S = -14V, V _D = 14V	-5.0	-0.02		1
SWITCH	Drain OFF Leakage Current	1	V _{IN} = 0.8V	V _S = 14V, V _D = -14V		0.01	5.0	nA
	Drain Of Fleakage Current	I _D (off)	VIN - 0.0V	V _S = -14V, V _D = 14V	-5.0	-0.02] '''`
	Drain ON Leakage Current		V _S = V _D = 14	V, V _{IN} = 2.4V		0.1	5.0	
	(Note 6)	D (on)	V _S = V _D = -1	4V, V _{IN} = 2.4V	-5.0	-0.15		
	Input Current With Input	1	V _{IN} = 2.4V		-1.0	-0.0004		
TUANI	Voltage High	INH	V _{IN} = 15V	V _{IN} = 15V		0.003	1.0	μΑ
<u>Z</u>	Input Current With Input Voltage Low	L _{INL}	V _{IN} = 0V		-1.0	-0.0004		
	Turn-ON Time	ton	See Switching Time			460	1000	
		t _{off1}		Test Circuit		360	500	ns
	Turn-OFF Time	t _{off2}	V _S = 2V	$V_S = 2V, R_L = 1k\Omega, C_L = 35pF$		450		
	Source OFF Capacitance	C _{S (off)}	V _S = 0V, V _{IN}	= 0V, f = 1MHz		5		
DYNAMIC	Drain OFF Capacitance	C _{D (off)}	V _D = 0V, V _{IN}	= 0V, f = 1MHz		5		pF
2	Channel ON Capacitance	C _{D+S(on)}	V _D = V _S = 0'	V, V _{IN} = 5V, f = 1MHz		16]
	OFF Isolation (Note 8)	OIRR)/ = 0\/ D	= 1kΩ, C ₁ = 15pF,		70		
	Crosstalk (Channel to Channel)	CCRR	$V_{\rm S} = 1 \text{VRMS}$	S, f = 100kHz		90		dB
	Positive Supply Current	1+				0.02	0.1	
≥	Negative Supply Current	1-	V _{IN} = 0V and	d 2.4V		0.00001	0.1	mA
SUPPLY	Logic Supply Current	I _L				0.0	0.0	
ะ	Power Supply Range for Continuous Operation	V _{OP}			±4.5		±18	v

Note 8: Electrical characteristics, such as ON Resistance, will change when power supplies, other than ±15V, are used.

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/VI/IXI/VI	:

ABSOLUTE MAXIMUM RATINGS (DG202)

Storage 1	Temperature65°C to	+150°C
Power D	issipation (Note 2)	
16 Pin	CERDIP (Note 3)	900mW
16 Pin	Plastic DIP (Note 4)	470mW
16 Pin	Small Outline (SE) (Note 5)	400mW
Note 1:	Signals on S _X , D _X , or IN _X exceeding V ⁺ or V ⁻ on MAX332 and DG202 will be clamped by internal	

and are also internally current limited to 25mA. Note 2:

Device mounted with all leads soldered to PC board.

Derate 12mW/°C above +75°C.

Derate 6.5mW/°C above +25°C. Note 3:

Note 4: Note 5: Derate 7mW/°C above +25°C.

Stresses listed under "Absolute Maximum Ratings" may be applied (one at a time) to devices without resulting in permanent damage. These are stress ratings only, and functional operation of the device at these or any other conditions above those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum ratings conditions for extended periods may affect device reliability.

ELECTRICAL CHARACTERISTICS (DG202)

 $(V^+ = +15V, V^- = -15V, GND = 0V, T_A = +25^{\circ}C, unless otherwise noted)$

								LIN	IITS	_		_
	PARAMETER	SYMBOL	TEST	TEST CONDITION			DG202A		D	G202B,	c	UNITS
				. Edi danamana			TYP (Note 7)	MAX	MIN (Note 6)	TYP (Note 7)	MAX	
	Analog Signal Range	V _{ANALOG}				-15		15	-15		15	٧
	Drain-Source ON Resistance	r _{DS (on)}	V _D = ±10V, V	_{IN} = 2.4V, I	I _S = 1mA		115	175		115	200	Ω
I	Source OFF Leakage		V _{IN} = 0.8V	V _S = 14V	, V _D = -14V		0.01	1.0		0.01	5.0	
TC	Current	S (off)	V _{IN} - 0.6V	V _S = -14	V, V _D = 14V	-5.0	-0.02					
SWITCH	Drain OFF Leakage	1	V _{IN} = 0.8V	V _S = 14V	, V _D = -14V		0.01	1.0		0.01	5.0	
	Current	D (off)	VIN - 0.6V	V _S = ~14	V, V _D = 14V	-5.0	-0.02					nA
	Drain ON Leakage		V _S = -14V, V _{II}	_N = 2.4V			0.1	1.0		0.1	5.0	
	Current (Note 8)	I _D (on)	V _D = 14V, V _{IN}	V _D = 14V, V _{IN} = 2.4V		-1.0	-0.15		-5.0	-0.15		
	Input Current With		V _{IN} = 2.4V	-		-1.0	-0.0004		-1.0	-0.0004		
INPUT	Input Voltage High	INH	V _{IN} = 15V	V _{IN} = 15V			0.003	1.0		0.003	1.0	μА
Ÿ	Input Current With Input Voltage Low	I _{INL}	V _{IN} = 0V			-1.0	-0.0004		-1.0	-0.0004		μ.
	Turn-ON Time	t _{on}	See S	Switching	Time		480	600		480	600	200
	Turn-OFF Time	t _{off}	T	est Circui	it ————		370	450		370	450	ns
	Charge Injection	Q	C _L = 10	00pF, V _{GE} R _{GEN} = 0Ω	_{EN} = 0V,		20			20		pC
DYNAMIC	Source OFF Capacitance	C _{S (off)}	V _S = 0V, V _{IN} =	= 0V			5			5		
Ž	Drain OFF Capacitance	C _{D (off)}	15 01, 1 _N	•	f = 140kHz		5			5		pF
6	Channel ON Capacitance	C _{D (on)} + C _{S (on)}	$V_D = V_S = 0V$	V _{IN} = 5V			16			16		
	OFF Isolation		$V_{IN} = 0V$, $Z_L = 75k\Omega$				70			70		
	Crosstalk (Channel to Channel)		V _S = 2.0V, f =	V _S = 2.0V, f = 100kHz			90			90		dВ
SUP- PLY	Positive Supply Current	1+	All Channels	ON or O	FF		0.9	2		0.9	2	mA
SI .	Negative Supply Current	I-	All Channels	ON or O	FF	-1	-0.3		-1	-0.3		'''`

Note 6: The algebraic convention whereby the most negative value is a minimum, and the most positive is a maximum, is used in this data sheet. Note 7:

Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing. Note 8: I_{D(on)} is leakage from driver into "ON" switch.

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♦ Significantly Reduced Power Consumption

♦ Lower Input Current Over Temperature

♦ No Input Current Spike

ABSOLUTE MAXIMUM RATINGS (MAX332, DG202): This device conforms to the Absolute Maximum Ratings on the adjacent page.

ELECTRICAL CHARACTERISTICS (MAX332, DG202): Specifications below satisfy or exceed all "tested" parameters on adjacent page.

(V⁺ = +15V, V⁻ = -15V, GND = 0V, T_A = +25° C, unless otherwise noted)

								LIN	MITS			
	PARAMETER	SYMBOL	TEST	CONDIT	IONS	MA)	(332/DG	202A	D	G202B,	С	UNITS
	PARAMETER	STIMBOL	1201	M		MIN (Note 6	TYP) (Note 7)	MAX	MIN (Note 6)	TYP (Note 7)	MAX	
	Analog Signal Range	VANALOG	-			-15		15	-15		15	٧
	Drain-Source ON Resistance (Note 9)	r _{DS (on)}	V _D = ±10V, V	/ _{IN} = 2.4V,	I _S = 1mA		115	175		115	200	Ω
픗	Source OFF Leakage		V -00V	V _S = 14	V, V _D = -14V 4V, V _D = 14V		0.01	1.0		0.01	5.0	
SWITCH	Current	S (off)				-1.0	-0.02		-5.0	-0.02]
Š	Drain OFF Leakage		V _{IN} = 0.8V	V _S = 14	V, V _D = -14V		0.01	1.0		0.01	5.0	nA
	Current	D (off)	V _{IN} - 0.6V	V _S = -14	4V, V _D = 14V	-1.0	-0.02		-5.0	-0.02] "A
	Drain ON Leakage		V _S = -14V, V	V _S = -14V, V _{IN} = 2.4V			0.1	1.0		0.1	5.0	
	Current (Note 8)	I _{D (on)}	V _D = 14V, V _{II}	_N = 2.4V		-1.0	-0.15		-5.0	-0.15		
	Input Current With		V _{IN} = 2.4V	V _{IN} = 2.4V			-0.0004		-1.0	-0.0004		
INPUT	Input Voltage High	INH	V _{IN} = 15V	V _{IN} = 15V			0.003	1.0		0.003	1.0] _{µA}
Z	Input Current With Input Voltage Low	INL	V _{IN} = 0V	V _{IN} = 0V			-0.0004		-1.0	-0.0004		
	Turn-ON Time	ton	See	Switching	Time		480	600		480	600	ns
	Turn-OFF Time	t _{off1}		Test Circi	uit		370	450		370	450] "
	Charge Injection	Q	C _L = 10	000pF, V _G R _{GEN} = 0:	iEN = 0V, Ω		20			20		рC
DYNAMIC	Source OFF Capacitance	C _{S (off)}	V _S = 0V, V _{IN}	= 0V			5			5		
ξ	Drain OFF Capacitance	C _{D (off)}		_	f = 140kHz		5			5		pF
_	Channel ON Capacitance	C _{D (on)} + C _{S (on)}	$V_D = V_S = 0V$	$V_D = V_S = 0V, V_{IN} = 5V$			16			16		<u> </u>
	OFF Isolation		$V_{IN} = 0V$, $Z_L = 75k\Omega$			70			70			
	Crosstalk (Channel to Channel)		V _S = 2.0V, f =	= 100kHz			90			90		dE
>	Positive Supply Current	1+	All Channel	s ON or 0	OFF		0.02	0.1		0.02	0.1	m/
SUPPLY	Negative Supply Current	1-	All Channel	s ON or (OFF	-0.1	-0.01		-0.1	-0.01		111/
SU	Power Supply Range for Continuous Operation	V _{OP}				±4.5		±18	±4.5		±18	v

The algebraic convention whereby the most negative value is a minimum, and the most positive is a maximum, is used in this Note 6:

Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing. Note 7:

Note 8: | D|con/ is leakage from driver into "ON" switch.

Note 9: | Electrical characteristics, such as ON Resistance, will change when power supplies other than ±15V, are used.

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ELECTRICAL CHARACTERISTICS (DG202)

(V⁺ = +15V, V⁻ = -15V, GND = 0V, T_A = Full Operating Temperature Range)

							LIN	AITS			
	PARAMETER	SYMBOL	TEST	CONDITIONS		DG202A		D	С	UNITS	
					MIN (Note 6)	TYP (Note 7)	MAX	MIN TYP (Note 6) (Note 7)	MAX		
	Analog Signal Range	V _{ANALOG}			-15		15	-15		15	V
	Drain-Source ON Resistance	r _{DS (on)}	V _D = ±10V, V	/ _{IN} = 2.4V, I _S = 1mA			250			250	Ω
I	Source OFF Leakage		V _{IN} ≈ 0.8V	V _S = 14V, V _D = -14V			100		_	100	† — —
SWITCH	Current	S (off)	V _{IN} = 0.6V	V _S = -14V, V _D = 14V	-100			-100			1
S	Drain OFF Leakage		V _{IN} ≈ 0.8V	V _S = 14V, V _D = -14V			100			100	1
	Current	D (off)	V _{IN} ~ 0.64	V _S = -14V, V _D = 14V	-100			-100			nA
	Drain ON Leakage		V _S = -14V, V	in = 2.4V			200			200	1
	Current (Note 10)	D (on)	V _D = 14V, V _{II}	v ≈ 2.4V	-200			-200			1
	Input Current With		V _{IN} = 2.4V		-1.0			-10			
INPUT	Input Voltage High	HMI	V _{IN} = 15V				-10			-10	1 .
Ź	Input Current With Input Voltage Low	I _{INL}	VIN = OV		-10			-10			μΑ

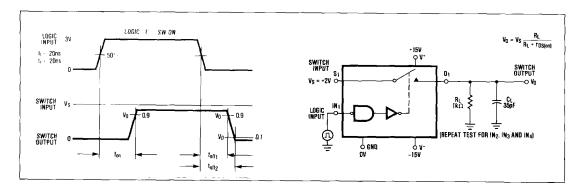
Note 10: I_{D(on)} is leakage from driver into "ON" switch.

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Switching Time Test Circuit

Switch output waveform shown for $\rm V_S=constant$ with logic input waveform as shown. Note that $\rm V_S$ may be +ve or -ve as per switching times test circuit.

 $V_{\rm O}$ is the steady state output with switch on. Feedthrough via gate capacitance may result in spikes at leading and trailing edge of output waveform.



Typical R_{DS(ON)} vs. Power Supplies for Maxim's MAX332, DG202/DG212

POWER SUPPLIES	R _{DS(ON)} AT ANALOG SIGNAL LEVEL						
	-5V	+5V	-10V	+10V	-15V	+15V	
±5V	350Ω	380Ω					
±10V			165Ω	250Ω	 		
±15V			125Ω	160Ω	135Ω	155()	



ELECTRICAL CHARACTERISTICS (MAX332, DG202):

($V^+ = +15V$, $V^- = -15V$, GND = 0V, $T_A = full$ operating temperature range)

		SYMBOL	TEST CONDITIONS		LIMITS						
	PARAMETER Analog Signal Range				MAX332/DG202A		DG202B,C		UNITS		
					MIN (Note 6)	TYP MAX (Note 7)	MIN (Note 6)	TYP (Note 7)	MAX	3.1.10	
					-15	15	-15		15	V	
	Drain-Source ON Resistance (Note 11)	r _{DS (on)}	$V_D = \pm 10V$, $V_{1N} = 2.4V$, $I_S = 1 \text{mA}$			250			250	Ω	
SWITCH	Source OFF Leakage Current	Is (off)	V _{IN} = 0.8V	V _S = 14V, V _D = -14V		100			100	nA	
				V _S = -14V, V _D = 14V	-100		-100				
	Drain OFF Leakage Current	I _{D (off)}	V _{IN} = 0.8V	V _S = 14V, V _D = -14V	1	100			100		
				$V_S = -14V, V_D = 14V$	-100		-100				
	Drain ON Leakage Current (Note 10)	I _{D (on)}	$V_S = -14V, V_{IN} = 2.4V$			200			200	-]	
			V _D = 14V, V _{IN} = 2.4V		-200		-200]	
INPUT	Input Current With Input Voltage High	I _{INH}	V _{IN} = 2.4V		-1.0		-1.0				
			V _{IN} = 15V		1.0				1.0	μА	
	Input Current With Input Voltage Low	I _{INL}	V _{IN} = 0V		-1.0		-1.0				

Note 10: I_{D(001)} is leakage from driver into "ON" switch.

Note 11: Electrical characteristics, such as ON Resistance, will change when power supplies other than ±15V, are used.

Fault conditions occur when power supplies are turned off when input signals are still present or when over voltages occur at the inputs during normal operation. In either case, source-to-body diodes can be forward biased and conduct current from the signal source. If this current is required to be kept to low (μ A) levels then the addition of external protec-

To provide protection for over-voltages up to 20V above the supplies, a 1N4001 or 1N914 type diode should be placed in series with the positive and negative supplies as shown in Fig. 1. The addition of these diodes will reduce the analog signal range to 1 volt below the positive supply and 1 volt above the negative supply.

tion diodes is recommended.

Protecting Against Fault Conditions

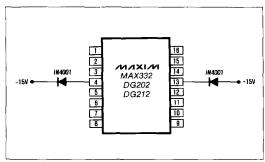
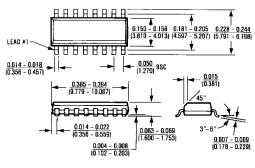


Figure 1. Protection Against Fault Conditions

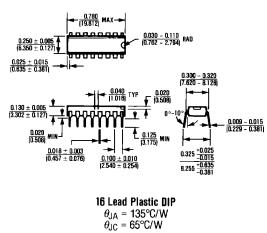
MIXIM

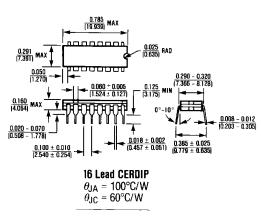
Chip Topography 03 IN3 IN4 D4 S2 IN2 IN1 D1 0.780 MAX (1.83 mm) 0.300 - 0.110 (0.782 - 2.794) RAD

Package Information



16 Lead Small Outline (SE) $\theta_{\rm JA} = 110^{\circ}{\rm C/W}$ $\theta_{\rm JC} = 60^{\circ}{\rm C/W}$





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